

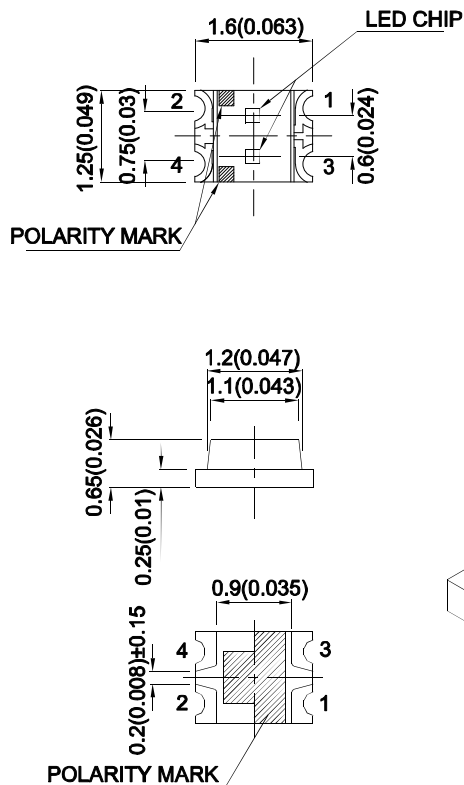


**ATTENTION**  
OBSERVE PRECAUTIONS  
FOR HANDLING  
ELECTROSTATIC  
DISCHARGE  
SENSITIVE  
DEVICES

### Features

- High reliability LED package.
- 1.6mmx1.25mm SMD LED, 0.65mm thickness.
- Bi-color, low power consumption.
- Wide viewing angle.
- Ideal for backlight and indicator.
- Package : 2000pcs / reel.
- Moisture sensitivity level : level 3.
- RoHS compliant.

### Package Dimensions



Part Number: APTB1612SYKQWDF-AMT

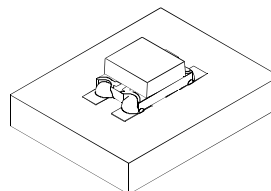
Super Bright Yellow  
White

### Description

- The Super Bright Yellow device is made with AlGaInP (on GaAs substrate) light emitting diode chip.
- The source color devices are made with InGaN Light Emitting Diode.
- Electrostatic discharge and power surge could damage the LEDs.
- It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs.
- All devices, equipments and machineries must be electrically grounded.

### Applications

- Traffic signaling.
- Backlighting (illuminated advertising , general lighting).
- Interior and exterior automotive lighting.
- Substitution of micro incandescent lamps.
- Reading lamps.
- Signal and symbol luminaire for orientation.
- Marker lights (e.g. Steps, exit ways, etc).
- Decorative and entertainment lighting.
- Indoor and outdoor commercial and residential architectural lighting.



#### Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is  $\pm 0.2(0.008)$  unless otherwise noted.
3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
4. The device has a single mounting surface. The device must be mounted according to the specifications.



## Selection Guide

Part No.	Emitting Color (Material)	Lens Type	Iv (mcd) [2] @ 20mA			Viewing Angle [1]
			Code.	Min.	Max.	2θ1/2
APT B1612SYKQWDF-AMT	Super Bright Yellow (AlGaInP)	Yellow Fluorescent	M	80	120	120°
			N	120	200	
			P	200	300	
	White (InGaN)		N	120	200	
			P	200	300	
			Q	300	400	

**Notes:**

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
2. Luminous intensity/ luminous Flux: +/-15%.
3. Luminous intensity value is traceable to the CIE127-2007 compliant national standards.

## Absolute Maximum Ratings at TA=25°C

Parameter	Symbol	Value		Unit
		Super Bright Yellow	White	
Power dissipation	P <sub>D</sub>	75	80	mW
Operating Temperature	T <sub>op</sub>	-40 To+ 100		°C
Storage Temperature	T <sub>stg</sub>	-40 To+ 110		°C
Junction temperature	T <sub>J</sub>	115	115	°C
DC Forward Current (TA=25°C)	I <sub>F</sub>	30	20	mA
Peak Forward Current [1] (TA=25°C)	I <sub>FM</sub>	175	150	mA
Reverse Voltage (TA=25°C)	V <sub>R</sub>	5	5	V
Electrostatic Discharge Threshold (HBM)		3000	250	V
Thermal resistance (Junction/ambient)	1 chip on (typ.)	R <sub>th j-a</sub>	620	°C/W
	2 chip on (typ.)	R <sub>th j-a</sub>	760	

**Note:**

1.1/10 Duty Cycle, 0.1ms Pulse Width.

## Electrical / Optical Characteristics at TA=25°C (Yellow)

Parameter	Symbol	Value				Unit
		Code.	Min.	Typ.	Max.	
Wavelength at peak emission IF=20mA	$\lambda$ peak			590		nm
Dominant Wavelength IF=20mA	$\lambda$ dom [1]	3	586		588	nm
		4	588		590	
		5	590		592	
		6	592		594	
Spectral bandwidth at 50% $\Phi$ REL MAX IF=20mA	$\Delta\lambda$			20		nm
Forward Voltage IF=20mA	V <sub>F</sub> [2]			2.0	2.5	V
Reverse Current (V <sub>R</sub> = 5V)	I <sub>R</sub>				10	uA
Temperature coefficient of $\lambda$ peak IF=20mA, -10 ° C ≤ T ≤ 100 ° C	TC <sub><math>\lambda</math> peak</sub>			0.12		nm/° C
Temperature coefficient of $\lambda$ dom IF=20mA, -10 ° C ≤ T ≤ 100 ° C	TC <sub><math>\lambda</math> dom</sub>			0.08		nm/° C
Temperature coefficient of V <sub>F</sub> IF=20mA, -10 ° C ≤ T ≤ 100 ° C	TC <sub>V</sub>			-1.8		mV/° C

Notes:

- The dominant Wavelength ( $\lambda$  d) above is the setup value of the sorting machine. (Tolerance  $\lambda$  d :  $\pm 1$ nm. )
- Forward Voltage: +/-0.1V.
- Wavelength value is traceable to the CIE127-2007 compliant national standards.
- Excess driving current and/or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

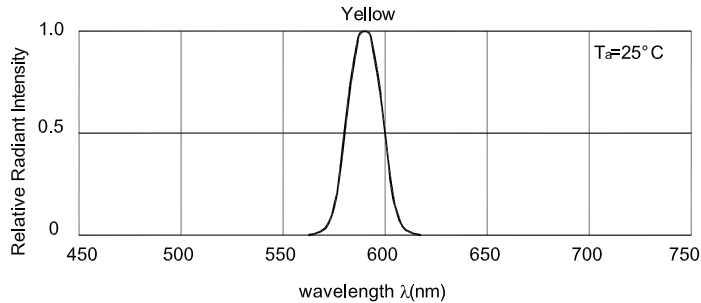
## Electrical / Optical Characteristics at TA=25°C (White)

Parameter	Symbol	Value	Unit
Chromaticity coordinate x acc.to CIE1931 IF=20mA [Typ.]	x [1]	0.31	
Chromaticity coordinate y acc.to CIE1931 IF=20mA [Typ.]	y [1]	0.31	
Reverse Current (V <sub>R</sub> = 5V) [Max.]	I <sub>R</sub>	50	uA
Forward Voltage IF=20mA [Min.]	V <sub>F</sub> [2]	-	V
Forward Voltage IF=20mA [Typ.]		3.3	
Forward Voltage IF=20mA [Max.]		4.0	
Temperature coefficient of V <sub>F</sub> IF=20mA, -10 ° C ≤ T ≤ 100 ° C [Typ.]	TC <sub>V</sub>	-2.0	mV/° C
Temperature coefficient of x IF=20mA, -10 ° C ≤ T ≤ 100 ° C [Typ.]	TC <sub>x</sub>	-0.18	10 <sup>-3</sup> /° C
Temperature coefficient of y IF=20mA, -10 ° C ≤ T ≤ 100 ° C [Typ.]	TC <sub>y</sub>	-0.20	10 <sup>-3</sup> /° C

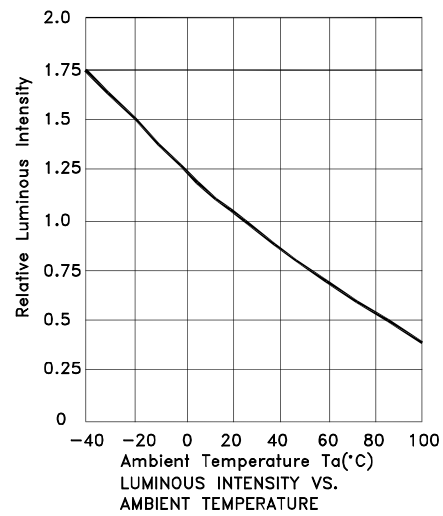
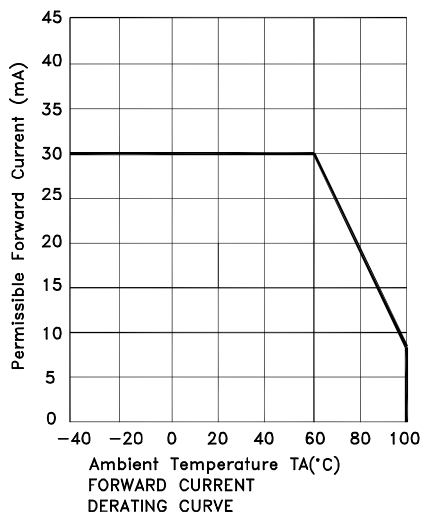
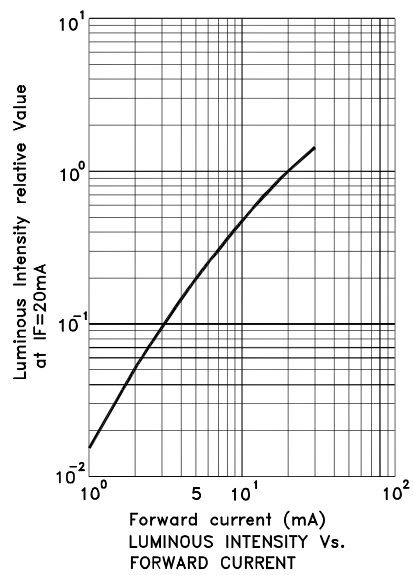
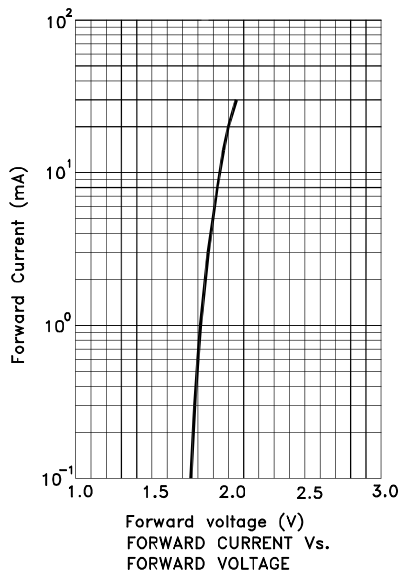
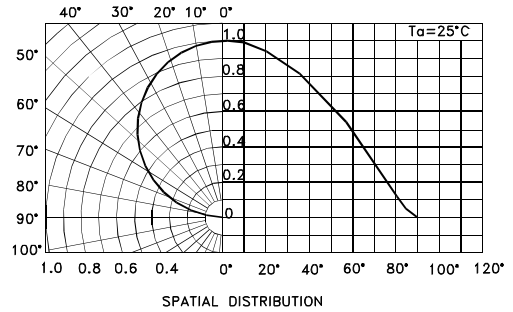
Notes:

- Measurement tolerance of the chromaticity coordinates is  $\pm 0.01$ .
- Forward Voltage: +/-0.1V.
- Excess driving current and/or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

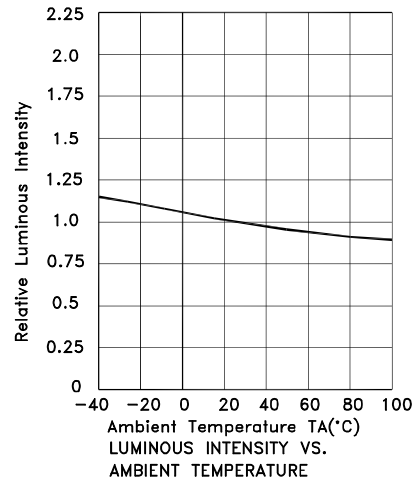
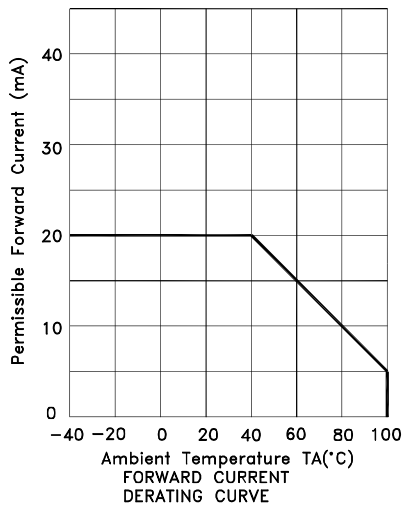
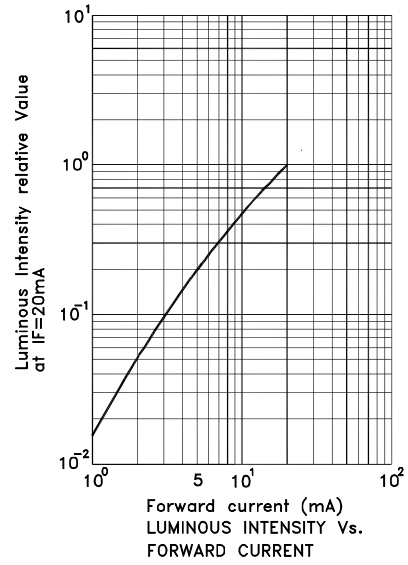
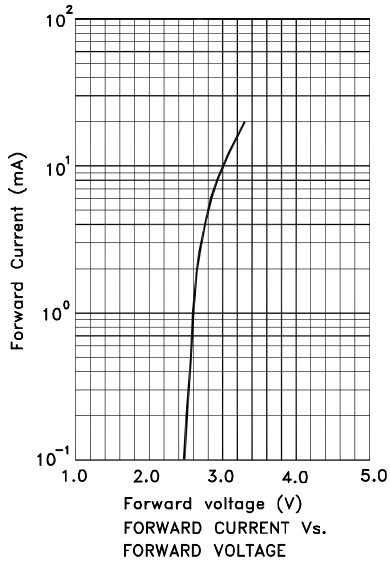
## APTB1612SYKQWDF-AMT Super Bright Yellow



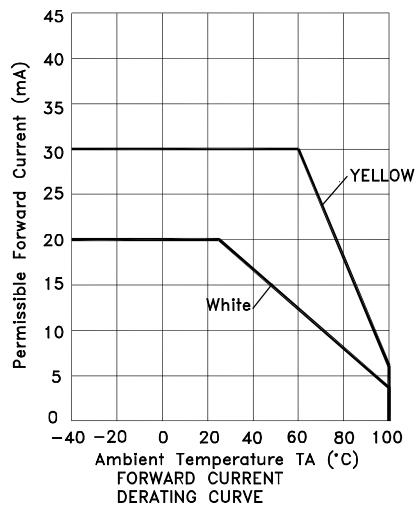
Relative Intensity Vs. Wavelength



## White

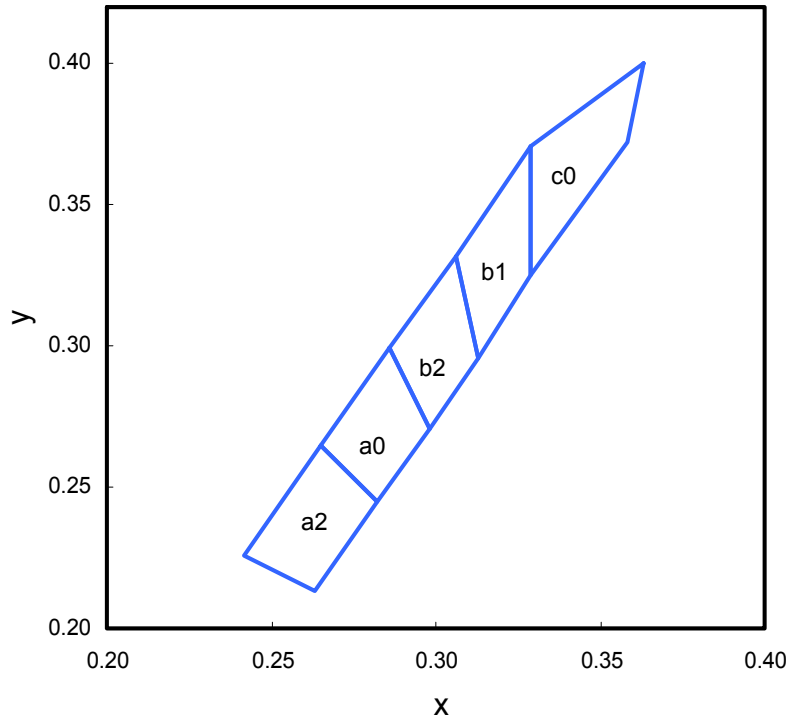


### All chip together



APTB1612SYKQWDF-AMT

## White CIE



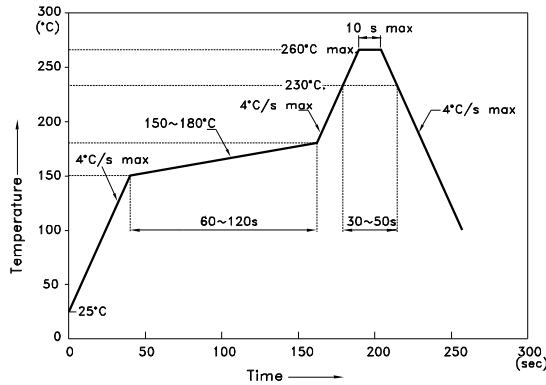
	x	y		x	y		x	y
a2	0.263	0.213	a0	0.282	0.245	b2	0.298	0.271
	0.282	0.245		0.298	0.271		0.313	0.296
	0.265	0.265		0.286	0.299		0.306	0.332
	0.242	0.226		0.265	0.265		0.286	0.299
b1	0.313	0.296	c0	0.329	0.325			
	0.329	0.325		0.358	0.372			
	0.329	0.371		0.363	0.400			
	0.306	0.332		0.329	0.371			

Notes:  
 Shipment may contain more than one chromaticity regions.  
 Orders for single chromaticity region are generally not accepted.  
 Measurement tolerance of the chromaticity coordinates is  $\pm 0.01$ .

## APTB1612SYKQWDF-AMT

Reflow soldering is recommended and the soldering profile is shown below.  
Other soldering methods are not recommended as they might cause damage to the product.

Reflow Soldering Profile For Lead-free SMT Process.

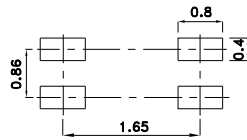


NOTES:

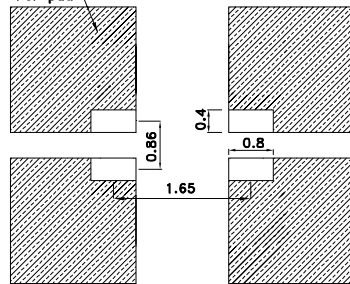
1. We recommend the reflow temperature 245°C (+/-5°C). The maximum soldering temperature should be limited to 260°C.
2. Don't cause stress to the epoxy resin while it is exposed to high temperature.
3. Number of reflow process shall be 2 times or less.

### Recommended Soldering Pattern (Units : mm; Tolerance: ± 0.1)

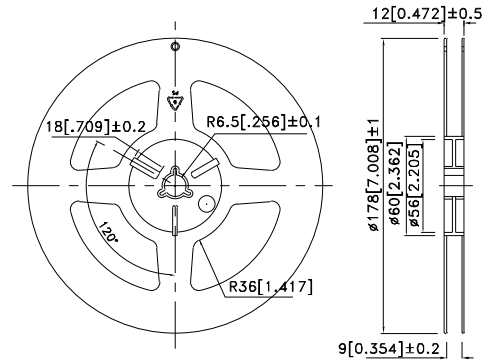
Pad design for Improved heat dissipation



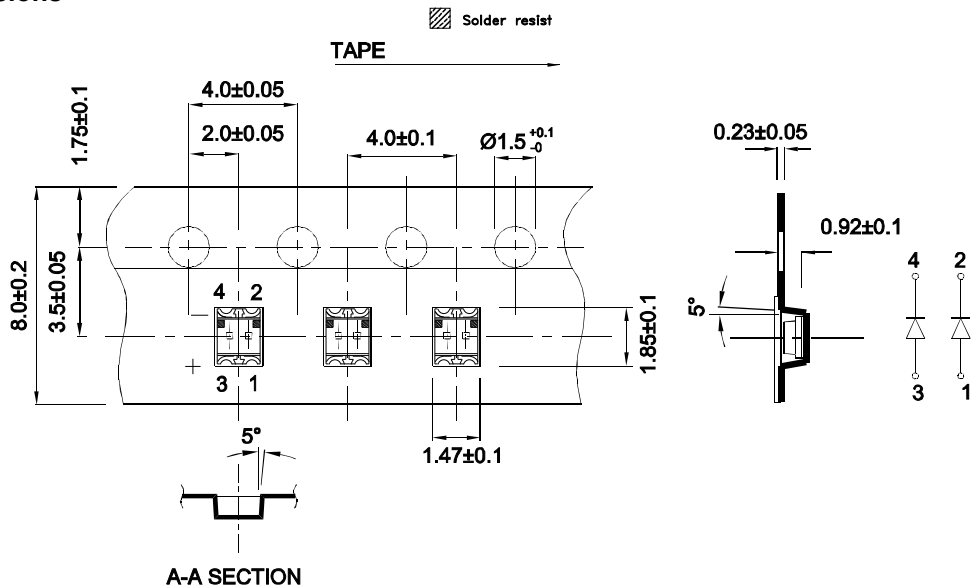
Cu-area ≥ 16mm<sup>2</sup>  
Per pad



### Reel Dimension



### Tape Dimensions (Units : mm)







## Reliability Test Items And Conditions

The reliability of products shall be satisfied with items listed below

**Lot Tolerance Percent Defective (LTPD) : 10%**

No.	Test Item	Standards	Test Condition	Test Times / Cycles	Number of Damaged
1	Continuous operating test	-	Ta =25°C ,IF = maximum rated current*	1,000 h	0 / 22
2	High Temp. operating test	EIAJ ED-4701/100(101)	Ta = 100°C IF =derated current at 100°C	1,000 h	0 / 22
3	Low Temp. operating test	-	Ta = -40°C, IF = maximum rated current*	1,000 h	0 / 22
4	High temp. storage test	EIAJ ED-4701/100(201)	Ta = maximum rated storage temperature	1,000 h	0 / 22
5	Low temp. storage test	EIAJ ED-4701/100(202)	Ta = -40°C	1,000 h	0 / 22
6	High temp. & humidity storage test	EIAJ ED-4701/100(103)	Ta = 60°C, RH = 90%	1,000 h	0 / 22
7	High temp. & humidity operating test	EIAJ ED-4701/100(102)	Ta = 60°C, RH = 90% IF = derated current at 60°C	1,000 h	0 / 22
8	Resistance to Soldering Heat	EIAJ ED-4701/100(301)	TSId=260±5°C, 10 sec	2 times	0 / 18
9	Thermal shock operating test	-	Ta = -40°C(15min) ~ 100°C(15min) IF = derated current at 100°C	1,000 cycles	0 / 22
10	Thermal shock test	-	Ta = -40°C(15min) ~ 100°C(15min)	1,000 cycles	0 / 22
11	Electric Static Discharge (ESD)	EIAJ ED-4701/100(304)	C = 100pF , R2 = 1.5KΩ V=3000V(Yellow) V = 250V(White)	Once each Polarity	0 / 22
12	Vibration test	-	a = 196m/s <sup>2</sup> , f = 100~2KHz , t = 48min for all xyz axes	4 times	0 / 22

\* : Refer to forward current vs. derating curve diagram

## Failure Criteria

Items	Symbols	Conditions	Failure Criteria
luminous Intensity	Iv	IF = 20mA	Testing Min. Value <Spec.Min.Value x 0.5
Forward Voltage	VF	IF = 20mA	Testing Max. Value ≥Spec.Max.Value x 1.2
Reverse Current	IR	VR = Maximum Rated Reverse Voltage	Testing Max. Value ≥Spec.Max.Value x 2.5
High temp. storage test	-	-	Occurrence of notable decoloration, deformation and cracking